WHAT IS CLAIMED IS:

- 1. An island projection-modified part which has, on the substrate thereof, island projections having a width of from 5 to 300 μ m and a height of from 2 to 200 μ m and in which the island projections are roundish as a whole and the number of the island projections is from 20 to 5,000/mm².
- 2. The island projection-modified part as claimed in claim 1, wherein the island projections are formed of glass and they are spherical, partly spherical, semispherical, bell-shaped or mountain-shaped or are in the form of a mixture of two or more of these shapes.
- 3. The island projection-modified part as claimed in claim 1, wherein the island projections are formed on a glass-sprayed film that is formed on the substrate.
- 4. The island projection-modified part as claimed in claim 2, wherein the glass to form the island projections is quartz glass.
- 5. The island projection-modified part as claimed in claim 3, wherein the sprayed film is of quartz glass.
- 6. A method for producing the projection-modified part of claim 1, which comprises plasma-spraying a projection-forming material on the surface of a substrate or on the surface of a glass-sprayed film formed on a substrate to thereby form island projections thereon and in which the amount of the projection-forming material to be sprayed on the surface is from 1 to 20 mg/cm² of the area of that surface.

- 7. A film-forming device that comprises the island projection-modified part of claim 1.
- 8. A plasma-etching device wherein the island projection-modified part of claim 1 is used for the part on which a film may be deposited or etched through plasma etching.
- 9. A plasma-cleaning device wherein the island projection-modified part of claim 1 is used for the part on which a film may be deposited or etched through back sputtering.
- 10. The island projection-modified part as claimed in claim 1, wherein the island projections are formed of ceramic and/or metal, and they are mountain-shaped and/or bell-shaped.
- 11. The island projection-modified part as claimed in claim 1, wherein the mean ratio of the height to the width (height/width) of the island projections falls between 0.3 and 1.5.
- 12. The island projection-modified part as claimed in claim 10, wherein the surface of the substrate on which the island projections are formed has a surface roughness Ra of at most 5 μm .
- 13. The island projection-modified part as claimed in claim 10, wherein the island projections are formed of materials having a different melting point and the material having a high melting point is enveloped in the other material having a low melting point to give the island projections.

- 14. A method for producing the projection-modified part of claim 10, which comprises dashing a projection-forming material to the surface of a substrate while the material is in a semi-melted condition and in which the amount of the material to be applied to the surface is from 1 to 20 mg/cm² of the area of that surface.
- 15. A method for producing the island projection-modified part of claim 10, which comprises preparing a spraying powder of particles of a high-melting-point material enveloped in a low-melting-point material and dashing it to a substrate in a mode of thermal spraying while the low-melting-point material is completely melted but the high-melting-point material is un-melted or semi-melted.
- 16. The method as claimed in claim 14 for producing the island projection-modified part, wherein the substrate is, after thermally sprayed to have island projections formed thereon, further heated.
- 17. The method as claimed in claim 15 for producing the island projection-modified part, wherein the substrate is, after thermally sprayed to have island projections formed thereon, further heated.
- 18. A film-forming device wherein the part of claim 10 is used for the part that may receive a filmy deposit formed thereon through PVD or CVD.
- 19. A plasma-etching device wherein the part of claim 10 is used for the part on which a film may be deposited or etched through plasma etching.
- 20. A plasma-cleaning device wherein the part of claim 10 is used for the part on which a film may be deposited or etched through back sputtering.